

SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

LA6393M

Monolithic Linear IC For Parallel Comparator Circuits High-Performance Dual Comparator

Overview

The LA6393M is a high-performance dual comparator that is capable of operating from a single power supply over a wide range of 2V to 36V. Because of its excellent input characteristics and low power, it can be very conveniently applied to multi-signal parallel comparator circuits that require high-density assembly.

Features

- Wide operating supply voltage range: 2.0 to 36.0V (single voltage supply), ±1.0 to 18.0V (dual voltage supply)
- Wide common-mode input voltage range: 0 to V_{CC}-1.5V
- Open collector outputs allow the use of wired OR circuits
- Low current drain for low-power operation (0.6mA)
- Miniature flat package supports product miniaturization

Specifications

Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V _{CC} max		36	V
Differential input voltage	VID		36	V
Common-mode input voltage range	VICM		-0.6 to +36	V
Allowable power dissipation	Pd max	Independent IC	300	mW
Operating temperature	Topr		-30 to +85	°C
Storage temperature	Tstg		-55 to +150	°C

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LA6393M

Operating Ranges at Ta = 25°C

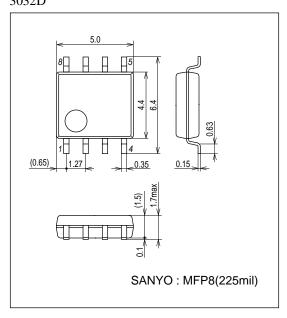
Parameter	Symbol	Conditions	Ratings	Unit
Recommended supply voltage	V _{CC} op	Single voltage supply	2 to 18	V
range		Dual voltage supply	±1 to ±18	V

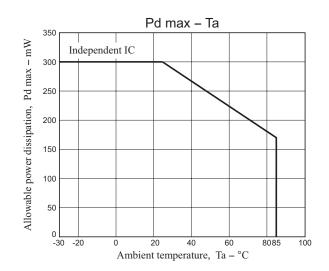
Electrical Characteristics at Ta = 25°C, $V_{CC} = 5V$

Parameter	Symbol	Conditions	Test circuit	Ratings			Unit
				min	typ	max	Unit
Input offset voltage	V _{IO}		1		±1	±5	mV
Input offset current	I _{IO}		2		±5	±50	nA
Input bias current	IB		3		25	250	nA
Common-mode input voltage range	VICM			0		V _{CC} -1.8	V
Current drain	ICC	R _L = ∞	4		0.6	1	mA
Voltage gain	V _G	$R_L = 15k\Omega$	5		200		V/mV
Response time	SR	$V_{RL} = 5 \text{ V}, R_L = 5.1 \text{k}\Omega$	6		1.3		μS
Output sink current	ISINK	V_{IN} -= 1V, V_{IN} + = 0V, $V_{O} \le 1.5$ V	7	6	16		mA
Output saturation voltage	V _{OL}	V_{IN} -= 1V, V_{IN} + = 0V, $I_{SINK} \le 3mA$	8		0.2	0.4	V
Output leakage current	ILEAK	$V_{IN}-=0V, V_{IN}+=1V, V_{O}=5V$	9		0.1		nA

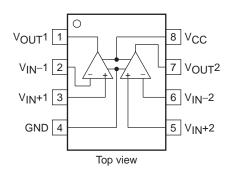
Package Dimensions

unit : mm (typ) 3032D

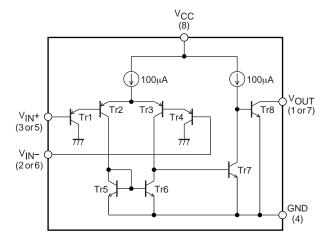




Pin Assignment

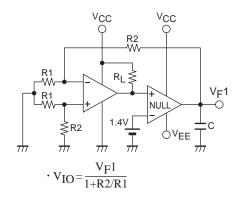


Equivalent Circuit

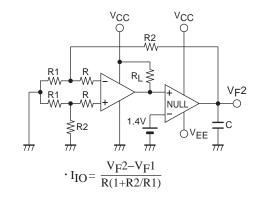


Test Circuit

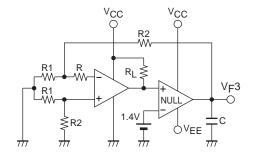
1. Input offset voltage

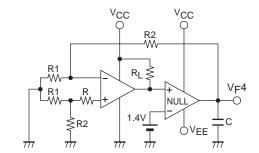


2. Input offset current



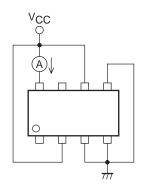
3. Input bias current



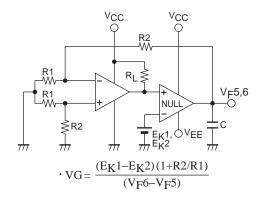


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$$I_B = \frac{|V_F 3 - V_F 4|}{2R(1 + R2/R1)}$$

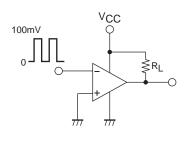
4. Current drain

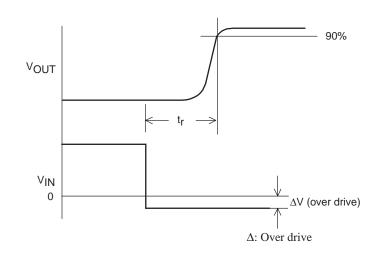


5. Voltage gain

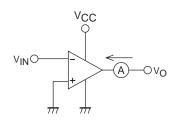


4. response time

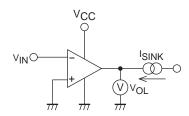




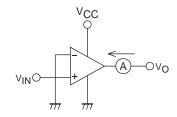
7. Output sink current

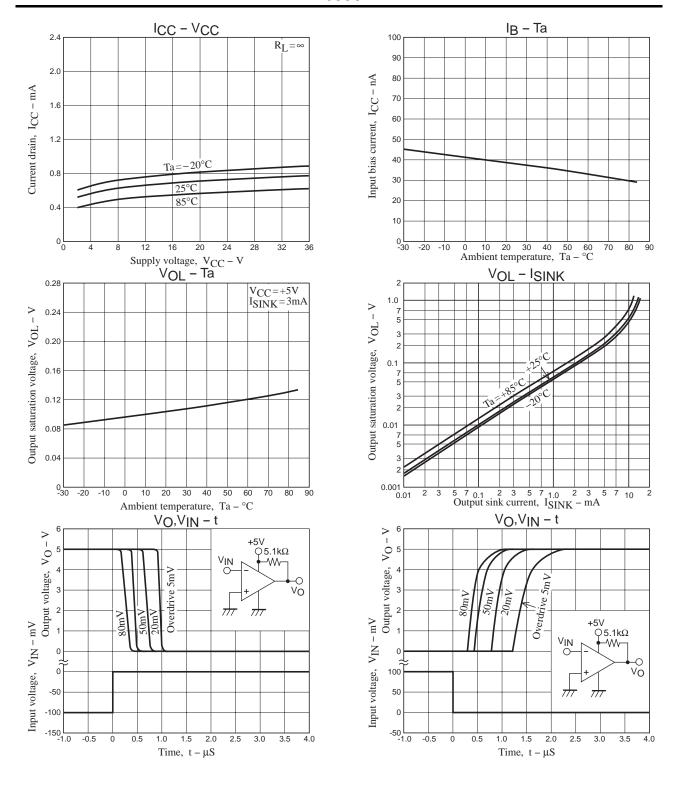


8. Output saturation voltage

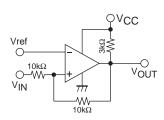


9. Output leakage current

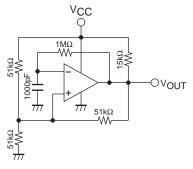




Application Circuit Example



Voltage comparator (with hysteresis)



Square wave generator

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